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March 1995 Revised March 2001

GTLP16612 18-Bit TTL/GTLP Universal Bus Transceiver

General Description

The GTLP16612 is an 18-bit universal bus transceiver which provides TTL to GTLP signal level translation. The device is designed to provide a high speed interface between cards operating at TTL logic levels and a backplane operating at GTLP logic levels. High speed backplane operation is a direct result of GTLP's reduced output swing (<1V), reduced input threshold levels and output edge rate control which minimizes signal settling times. GTLP is a Fairchild Semiconductor derivative of the Gunning Transceiver Logic (GTL) JEDEC standard JESD8-3.

Fairchild's GTLP has internal edge-rate control and is Process, Voltage, and Temperature (PVT) compensated. Its function is similar to BTL or GTL but with different driver output levels and receiver threshold. GTLP output low voltage is typically less than 0.5V, the output high is 1.5V and the receiver threshold is 1.0V.

Features

- Bidirectional interface between GTLP and TTL logic levels
- Designed with an edge rate control circuit to reduce output noise on GTLP port
- V_{REF} pin provides external supply reference voltage for receiver threshold adjustability
- Special PVT compensation circuitry to provide consistent performance over variations of process, supply voltage and temperature
- TTL compatible Driver and Control inputs
- Designed using Fairchild advanced CMOS technology
- Bushold data inputs on A port to eliminate the need for external pull-up resistors for unused inputs
- Power up/down and power off high impedance for live insertion
- 5V tolerant inputs and outputs on LVTTL port
- Open drain on GTLP to support wired-or connection
- Flow-through pinout optimizes PCB layout
- D-type flip-flop, latch and transparent data paths
- A Port outputs source/sink −32 mA/+32 mA

Ordering Code:

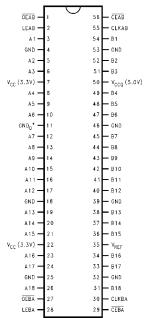
Order Number	Package Number	Package Description
GTLP16612MEA	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
GTLP16612MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code

Pin Descriptions

Pin Names	Description
OEAB	A-to-B Output Enable (Active LOW)
OEBA	B-to-A Output Enable (Active LOW)
CEAB	A-to-B Clock Enable (Active LOW)
CEBA	B-to-A Clock Enable (Active LOW)
LEAB	A-to-B Latch Enable (Transparent HIGH)
LEBA	B-to-A Latch Enable (Transparent HIGH)
CLKAB	A-to-B Clock Pulse
CLKBA	B-to-A Clock Pulse
V_{REF}	GTLP Input Reference Voltage
A1-A18	A-to-B TTL Data Inputs or
	B-to-A 3-STATE Outputs
B1-B18	B-to-A GTLP Data Inputs or
	A-to-B Open Drain Outputs

Connection Diagram



Functional Description

The GTLP16612 combines a universal transceiver function with a TTL to GTLP translation. The A Port and control pins operate at LVTTL or 5V TTL levels while the B Port operates at GTLP levels. The transceiver logic includes D-type latches and D-type flip-flops to allow data flow in transparent, latched and clock mode.

The functional operation is described in the truth table below.

Truth Table

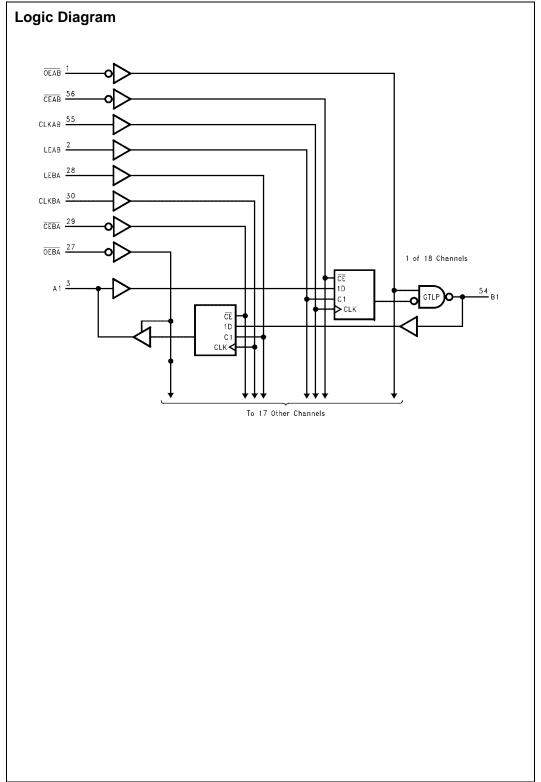
(Note 1)

Inputs					Output	Mode
CEAB	OEAB	LEAB	CLKAB	Α	В	
Х	Н	Х	Х	Χ	Z	Latched
L	L	L	Н	Х	B ₀ (Note 2)	storage
L	L	L	L	Х	B ₀ (Note 3)	of A data
Х	L	Н	Х	Г	L	Transparent
Х	L	Н	X	Н	Н	
L	L	L	1	Г	L	Clocked storage
L	L	L	\uparrow	Н	Н	of A data
Н	L	L	Х	Χ	B ₀ (Note 3)	Clock inhibit

Note 1: A-to-B data flow is shown. B-to-A data flow is similar but uses $\overline{\text{OEBA}}$, LEBA, CLKBA, and $\overline{\text{CEBA}}$.

Note 2: Output level before the indicated steady-state input conditions were established, provided that CLKAB was HIGH before LEAB went LOW.

Note 3: Output level before the indicated steady-state input conditions were established.



Absolute Maximum Ratings(Note 4)

Recommended Operating Conditions (Note 6)

 $\label{eq:supply Voltage VCC} \begin{array}{ll} \text{Supply Voltage (V}_{\text{CC}}, \text{V}_{\text{CCQ}}) & -0.5 \text{V to } +7.0 \text{V} \\ \text{DC Input Voltage (V}_{\text{I}}) & -0.5 \text{V to } +7.0 \text{V} \\ \end{array}$

DC Input Voltage (V_I) = -0.5V to + DC Output Voltage (V_O)

 $\begin{array}{ll} \mbox{Outputs 3-STATE} & -0.5\mbox{V to } +7.0\mbox{V} \\ \mbox{Outputs Active (Note 5)} & -0.5\mbox{V to } \mbox{V}_{\rm CC} + 0.5\mbox{V} \\ \end{array}$

DC Output Sink Current into

A Port I_{OL} 64 mA

DC Output Source Current from

A Port I_{OH} –64 mA

DC Output Sink Current

into B Port in the LOW State, I_{OL} 80 mA

DC Input Diode Current (I_{IK}) $V_{I} < 0V \qquad \qquad -50 \text{ mA} \label{eq:potential}$

DC Output Diode Current (I_{OK})

 $\begin{array}{ccc} V_{O} < 0V & -50 \text{ mA} \\ V_{O} > V_{CC} & +50 \text{ mA} \\ \text{Storage Temperature (T}_{STG}) & -65^{\circ}\text{C to } +150^{\circ}\text{C} \end{array}$

ESD Performance >2000V

Supply Voltage V_{CC}

 $\begin{array}{c} \rm V_{CC} & 3.15V \ to \ 3.45V \\ \rm V_{CCQ} & 4.75V \ to \ 5.25V \\ \rm Bus \ Termination \ Voltage \ (V_{TT}) & 1.35V \ to \ 1.65V \\ \end{array}$

Input Voltage (V_I)

on A Port and Control Pins 0.0V to 5.5V

HIGH Level Output Current (I_{OH})

A Port -32 mA

LOW Level Output Current (I_{OL})

A Port +32 mA B Port +34 mA Operating Temperature (T_A) -40°C to +85°C

Note 4: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be

Max

the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristic tables are not guaranteed at the absolute maximum rating. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 5: I_O Absolute Maximum Rating must be observed.

Note 6: Unused inputs must be held HIGH or LOW.

DC Electrical Characteristics

Over Recommended Operating Free-Air Temperature Range, V_{REF} = 1.0V (Unless Otherwise Noted).

	Symbol	Test Condit	tions	Min	(Note 7)	Max	Units
V _{IH}	B Port			V _{REF} +0.1		V _{TT}	V
	Others			2.0			V
V _{IL}	B Port			0.0		V _{REF} -0.1	V
	Others					0.8	Ť
V _{REF}					1.0		V
V _{IK}		V _{CC} = 3.15V,	I _I = -18 mA			-1.2	V
		V _{CCQ} = 4.75V	11 - 10 1111			-1.2	V
V _{OH}	A Port	V _{CC} , V _{CCQ} = Min to Max (Note 8)	$I_{OH} = -100 \mu A$	V _{CC} - 0.2			
		V _{CC} = 3.15V	$I_{OH} = -8 \text{ mA}$	2.4			V
		V _{CCQ} = 4.75V	$I_{OH} = -32 \text{ mA}$	2.0			Ī
V _{OL}	A Port	V _{CC} , V _{CCQ} = Min to Max (Note 8)	I _{OL} = 100 μA			0.2	
		V _{CC} = 3.15V	I _{OL} = 32 mA			0.5	V
		V _{CCQ} = 4.75V					
	B Port	$V_{CC} = 3.15 V V_{CCQ} = 4.75 V$	I _{OL} = 34 mA			0.65	V
I _I	Control Pins	V _{CC} , V _{CCQ} = 0 or Max	V _I = 5.5V or 0V			±10	μΑ
	A Port	V _{CC} = 3.45V	$V_{I} = 5.5V$			20	
		V _{CCQ} = 5.25V	$V_I = V_{CC}$			1	μΑ
			$V_I = 0$			-30	Ī
	B Port	V _{CC} = 3.45V	$V_I = V_{CCQ}$			5	
		V _{CCQ} = 5.25V	$V_I = 0$			-5	μΑ
I _{OFF}	A Port	$V_{CC} = V_{CCQ} = 0$	V_I or $V_O = 0$ to 4.5V			100	μΑ
I _{I(hold)}	A Port	$V_{CC} = 3.15V,$	$V_{I} = 0.8V$	75			μА
, ,		V _{CCQ} = 4.75V	$V_{I} = 2.0V$	-20			μΑ
I _{OZH}	A Port	$V_{CC} = 3.45V,$	V _O = 3.45V			1	
	B Port	V _{CCQ} = 5.25V	$V_0 = 1.5V$			5	μΑ
I _{OZL}	A Port	V _{CC} = 3.45V,	V _O = 0			-20	
	B Port	V _{CCO} = 5.25V	V _O = 0.65V			-10	μΑ

DC Electrical Characteristics (Continued)

	Symbol	Test	Conditions	Min	Typ (Note 7)	Max	Units
Icco	A or B	$V_{CC} = 3.45V,$	Outputs HIGH		30	40	
(V _{CCQ})	Ports	$V_{CCQ} = 5.25V$,	Outputs LOW		30	40	mA
		$I_{O} = 0$,					IIIA
		$V_I = V_{CCQ}$ or GND	Outputs Disabled		30	40	
I _{CC}	A or B	$V_{CC} = 3.45V,$	Outputs HIGH		0	1	
(V _{CC})	Ports	$V_{CCQ} = 5.25V$,	Outputs LOW		0	1	mA
		$I_{O} = 0$,					IIIA
		$V_I = V_{CCQ}$ or GND	Outputs Disabled		0	1	
ΔI_{CC}	A Port and	$V_{CC} = 3.45V,$	One Input at 2.7V		0	1	
(Note 9)	Control Pins	$V_{CCQ} = 5.25V$,					mA
		A or Control Inputs at					mA
		V _{CC} or GND					
C _{IN}	Control Pins		$V_I = V_{CCQ}$ or 0		8		
C _{I/O}	A Port		$V_I = V_{CCQ}$ or 0		9		pF
C _{I/O}	B Port		$V_I = V_{CCQ}$ or 0		6		1

Note 7: All typical values are at $V_{CC} = 3.3V$, $V_{CCQ} = 5.0V$, and $T_A = 25^{\circ}C$.

AC Operating Requirements

Over recommended ranges of supply voltage and operating free-air temperature, $V_{REF} = 1.0V$ (unless otherwise noted).

Symbol			Min	Max	Unit
f _{MAX}	Maximum Clock Frequency		150		MHz
t _W	Pulse Duration	LEAB or LEBA HIGH	3.0		
		CLKAB or CLKBA HIGH or LOW	3.2		ns
t _S	Setup Time	A before CLKAB↑	0.5		
		B before CLKBA↑	3.1		
		A before LEAB↓	1.3		
		B before LEBA↓	3.7		ns
		CEAB before CLKAB↑	0.4		
		CEBA before CLKBA↑	1.0		
t _H Hold Time	Hold Time	A after CLKAB↑	1.5		
		B after CLKBA↑	0.0		
		A after LEAB↓	0.5		
		B after LEBA↓	0.0		ns
		CEAB after CLKAB↑	1.5		
		CEBA after CLKBA↑	1.7		

Note 8: For conditions shown as Min or Max, use the appropriate value specified under recommended operating conditions.

 $[\]textbf{Note 9:} \ \ \textbf{This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} \ or \ GND.$

AC Electrical Characteristics

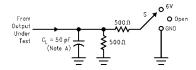
Over recommended range of supply voltage and operating free-air temperature, $V_{REF} = 1.0V$ (unless otherwise noted). $C_L = 30$ pF for B Port and $C_L = 50$ pF for A Port.

Symbol	From	То	Min	Тур	Max	Unit
	(Input)	(Output)		(Note 10)		
PLH	А	В	1.0	4.3	6.5	
PHL			1.0	5.0	8.2	ns
PLH	LEAB	В	1.8	4.5	6.7	
PHL			1.5	5.3	8.6	ns
PLH	CLKAB	В	1.8	4.6	6.7	
PHL			1.5	5.4	8.7	ns
PLH	OEAB	В	1.6	4.4	6.2	
PHL			1.3	6.1	9.8	ns
RISE	Transition time, B o	utputs (20% to 80%)		2.6		ns
FALL	Transition time, B o	utputs (20% to 80%)		2.6		
PLH	В	А	2.0	5.6	8.2	ns
PHL			1.4	5.0	7.2	120
PLH	LEBA	А	2.1	4.2	6.3	ns
PHL			1.9	3.3	5.0	115
PLH	CLKBA	А	2.3	4.4	6.8	ns
PHL			2.2	3.5	5.2	115
_{PZH} , t _{PZL}	OEBA	А	1.5	5.0	6.2	200
PHZ, t _{PLZ}			1.9	3.9	7.9	ns

Note 10: All typical values are at $V_{CC} = 3.3 V$, $V_{CCQ} = 5.0 V$, and $T_A = 25 ^{\circ} C$.

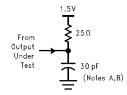
Test Circuits and Timing Waveforms

Test Circuit for A Outputs



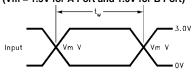
C_L includes probes and jig capacitance.

Test Circuit for B Outputs

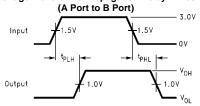


 ${
m C_L}$ includes probes and jig capacitance. For B Port outputs, ${
m C_L}=30$ pF is used for worst case edge rate.

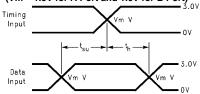
Voltage Waveforms Pulse Duration (Vm = 1.5V for A Port and 1.0V for B Port)



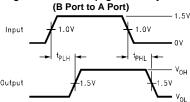
Voltage Waveforms Propagation Delay Times



Voltage Waveforms Setup and Hold Times (Vm = 1.5V for A Port and 1.0V for B Port) 3.0V

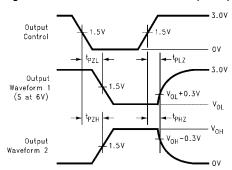


Voltage Waveforms Propagation Delay Times

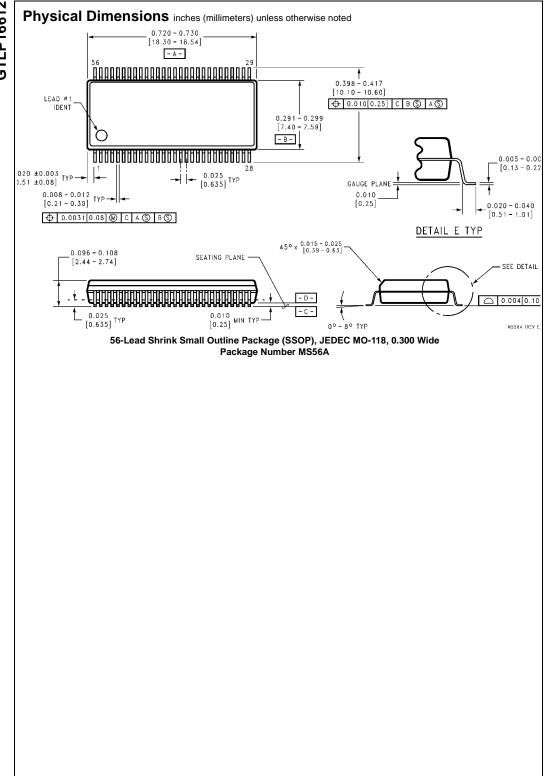


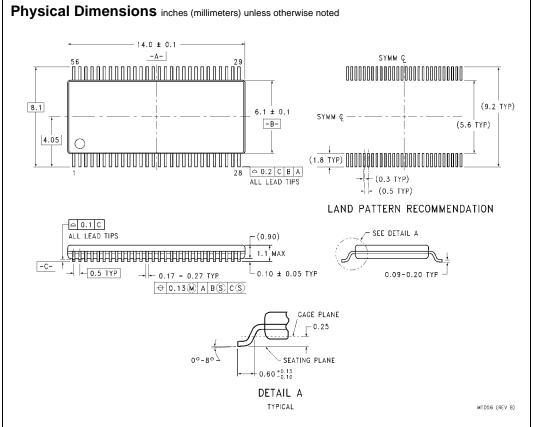
All input pulses have the following characteristics: frequency = 10 MHz, $t_r = t_f = 2$ ns, $Z_O = 50\Omega$. The outputs are measured one at a time with one transition per measurement.

Voltage Waveforms Enable and Disable Times (A Port)



Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is HIGH except when disabled by the output control. All input pulses have the following characteristics: frequency = 10 MHz, $t_r = t_f = 2$ ns, $Z_O = 50\Omega$. The outputs are measured one at a time with one transition per measurement.





56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Package Number MTD56

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